TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WB66FK

Dual Bus Switch

The TC7WB66FK is a low on-resistance, high-speed CMOS2-bit bus switch. This bus switch allows the connections or disconnections to be made with minimal propagation delay while maintaining Low power dissipation which is the feature of CMOS.

When output enable (OE) is at High level, the switch is on; when at Low level, the switch is off.

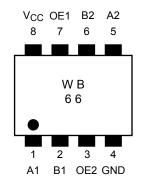
P-MOS and N-MOS channel block means the device is suitable for analog signal transmission.

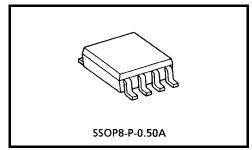
All inputs are equipped with protector circuits to protect the device from static discharge.

Features

- Operating voltage: $V_{CC} = 2 \sim 5.5 \text{ V}$
- High speed operation: $t_{pd} = 0.25 \text{ ns} (\text{max})$
- Ultra-low on resistance: $R_{ON} = 5 \Omega$ (typ.)
- ESD performance: Machine model $\ge \pm 200 \text{ V}$ Human body model $\ge \pm 2000 \text{ V}$
- High noise margin: $V_{NIL} = V_{NIH} = 28\% V_{CC}$ (min)
- Power-down protection for inputs (control inputs only)
- Package: US8

Pin Assignment (top view)





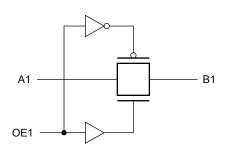
Weight: 0.01 g (typ.)

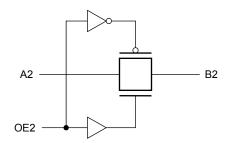
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Truth Table

Inputs	Function	
OE	FUNCTION	
Н	A port = B port	
L	Disconnect	

System Diagram





Absolute Maximum Ratings (Note)

Characteristics		Symbol	Rating	Unit	
Power supply volta	age	V _{CC}	-0.5~7.0	V	
Control pin input v	oltage	V _{IN}	-0.5~7.0	V	
Switch terminal I/O voltage		VS	$-0.5 \sim V_{CC} + 0.5$	V	
Clump diode current	Control input pin	lu c	-50	mA	
	Switch terminal	lік	±50	ША	
Switch I/O current		۱ _S	128	mA	
Power dissipation		PD	200	mW	
DC V _{CC} /GND current		I _{CC} /I _{GND}	±100	mA	
Storage temperature		T _{stg}	T _{stg} –65~150		

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	2.0~5.5	V
Control pin input voltage	V _{IN}	0~5.5	V
Switch I/O voltage	VS	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Control pin input rise/fall time	dt/dv	0~10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics (Ta = -40~85°C)

Character	istics	Symbol	Test Condition	V _{CC} (V)	Min	Typ. (Note 1)	Max	Unit
Control pin input	"H" level	VIH	_	2.0~5.5	$0.7 \times V_{CC}$	—	_	V
voltage			_	2.0~5.5	_	_	$0.3 \times V_{CC}$	V
Control pin input I current	eakage	I _{IN}	V _{IN} = 0~5.5 V	2.0~5.5	_	_	±1.0	μA
Off-state leakage (switch off)	current	I _{SZ}	A, B = 0~V _{CC} , OE = GND	2.0~5.5	_	_	±1.0	μΑ
			V _{IS} = 0 V, I _{IS} = 30 mA	4.5		3	7	
			V _{IS} = 4.5 V, I _{IS} = 30 mA	4.5	_	5	15	
		R _{ON}	$V_{IS} = 2.4 \text{ V}, I_{IS} = 15 \text{ mA}$	4.5	_	6	12	
ON resistance (Note 2)	$V_{IS} = 0 V, I_{IS} = 24 mA$		3.0	_	4	9	Ω	
	$V_{IS} = 3 V, I_{IS} = 24 mA$		3.0	_	7	20		
	$V_{IS} = 0 V, I_{IS} = 8 mA$		2.0		6	12		
			$V_{IS} = 2 V$, $I_{IS} = 8 mA$	2.0	_	10	30	
Quiescent supply	current	ICC	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	5.5	_		10	μA

Note 1: The typical values are at $Ta = 25^{\circ}C$.

Note 2: Apply the specified current to the switch, then measure the voltages on pins A and B. The on-resistance is the lower of the two.

AC Characteristics ($Ta = -40 \sim 85^{\circ}C$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	t _{pLH} Figure 1, Figure 2 (Note)	$\begin{array}{c} 2.0\\ 3.3\pm0.3 \end{array}$	_	0.5 0.35	ns
(bus to bus)	t _{pHL}		5.0 ± 0.5		0.25	
Output enable time	^t pZL ^t pZH	Figure 1, Figure 3	2.0	_	11.5	ns
			$\textbf{3.3}\pm\textbf{0.3}$	_	6	
			5.0 ± 0.5		4.5	
Output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.0	_	11.5	
			$\textbf{3.3}\pm\textbf{0.3}$	_	6.5	ns
			5.0 ± 0.5	_	5	

Note: The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

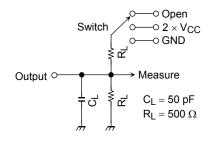
Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Control pin input capacitance	C _{IN}	(Note) 5.0	3	pF
Switch terminal capacitance	C _{I/O}	OE = GND (Note) 5.0	10	pF

Note: Guaranteed by design.

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AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	$2 \times V_{CC}$
t _{pHZ} , t _{pZH}	GND



AC Waveform

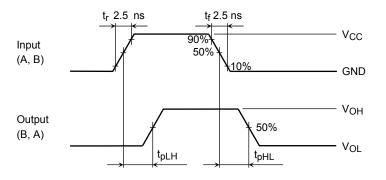
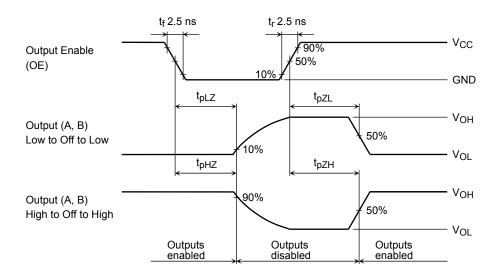
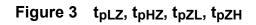


Figure 2 t_{pLH}, t_{pHL}

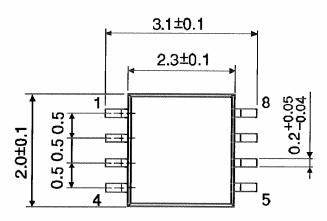


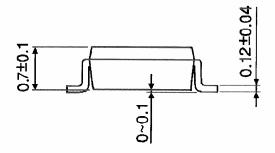


Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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